

0105-100

100 Watts, 28 Volts, Class AB Defcom 100 - 500 MHz

GENERAL DESCRIPTION

The 0105-100 is a double input matched COMMON EMITTER broadband transistor specifically intended for use in the 100-500 MHz frequency band. It may be operated in Class AB or C. Gold metallization and silicon diffused resistors ensure ruggedness and high reliability.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C 270 Watts

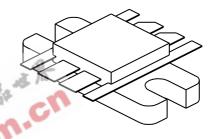
Maximum Voltage and Current

BVcesCollector to Emiter Voltage65 VoltsBVeboEmitter to Base Voltage4.0 VoltsIcCollector Current16 A

Maximum Temperatures

Storage Temperature - 40 to +150 °C Operating Junction Temperature +200 °C

CASE OUTLINE 55JT, Style 2



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin	Power Output Power Input	F = 500 MHz Vcc = 28 Volts	100	18	24	Watts Watts
Pg ηc VSWR	Power Gain Efficiency Load Mismatch Tolerance		6.2	7.5 50	5:1	dB %

BVebo BVces BVceo	Emitter to Base Breakdown Collector to Emitter Breakdown Collector to Emitter Breakdown	Ie = 5 mA Ic = 100 mA Ie = 50 mA	4.0 60 31			Volts Volts Volts
Cob ²	Output Capacitance	Vcb = 28 V, F = 1 MHz		140		pF
$\mathbf{h}_{ extbf{FE}}$	DC - Current Gain	Vce = 5 V, Ic = 500 mA	10			
θ jc	Thermal Resistance				0.65	°C/W

Note 2: Both sides together, all other specifications each side tested separately

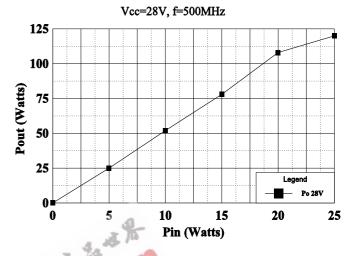
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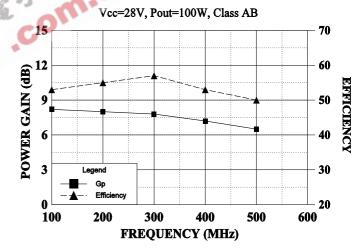


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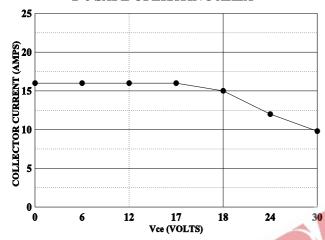
POWER OUTPUT vs POWER INPUT



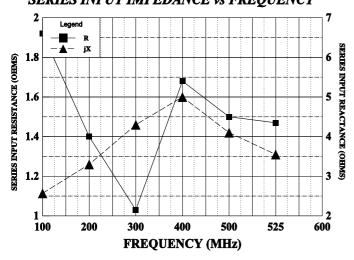
PERFORMANCE VS FREQUENCY







SERIES INPUT IMPEDANCE vs FREQUENCY



SERIES LOAD IMPENDANCE vs FREQUENCY

